

#### November 2014

## **FCPF400N80ZL1** N-Channel SuperFET<sup>®</sup> II MOSFET 800 V, 11 A, 400 mΩ

### Features

- Typ. R<sub>DS(on)</sub> = 340 mΩ
- Ultra Low Gate Charge (Typ. Q<sub>q</sub> = 43 nC)
- Low E<sub>oss</sub> (Typ. 4.1 uJ @ 400 V)
- Low Effective Output Capacitance (Typ. C<sub>oss(eff.)</sub> = 138 pF)
- 100% Avalanche Tested
- RoHS Compliant
- ESD Improved Capability

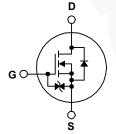
### Applications

- AC-DC Power Supply
- LED Lighting

### Description

SuperFET<sup>®</sup> II MOSFET is Fairchild Semiconductor's brand-new high voltage super-junction (SJ) MOSFET family that is utilizing charge balance technology for outstanding low on-resistance and lower gate charge performance. This technology is tailored to minimize conduction loss, provide superior switching performance, dv/dt rate and higher avalanche energy. In addition, internal gate-source ESD diode allows to withstand over 2kV HBM surge stress. Consequently, SuperFET II MOSFET is very suitable for the switching power applications such as Audio, Laptop adapter, Lighting, ATX power and industrial power applications.





#### Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted.

Symbol	Parameter			FCPF400N80ZL1	Unit	
V <sub>DSS</sub>	Drain to Source Voltage			800	V	
V <sub>GSS</sub>	Cata ta Sauraa Valtara	- DC		±20	V	
	Gate to Source Voltage	- AC	(f >1 Hz)	±30	V	
ID	Drain Current	- Continuous (T <sub>C</sub> = 25 <sup>o</sup> C)		11*	— A	
		- Continuous (T <sub>C</sub> = 100 <sup>o</sup> C)		6.9*		
I <sub>DM</sub>	Drain Current	- Pulsed (Note 1)		33*	Α	
E <sub>AS</sub>	Single Pulsed Avalanche Energy (Not			339	mJ	
I <sub>AR</sub>	Avalanche Current	(Note 1)	2.2	Α		
E <sub>AR</sub>	Repetitive Avalanche Energy		(Note 1)	0.36	mJ	
dv/dt	MOSFET dv/dt			100	Mag	
	Peak Diode Recovery dv/dt (No			20	V/ns	
P <sub>D</sub>	Dower Discinction	(T <sub>C</sub> = 25 <sup>o</sup> C)		35.7	W	
	Power Dissipation	- Derate Above 25°C		0.29	W/ºC	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range			-55 to +150	°C	
TL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds			300	°C	

\*Drain current limited by maximum junction temperature.

### Thermal Characteristics

Symbol	Parameter	FCPF400N80ZL1	Unit	
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	3.5	°C/W	
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient, Max.	62.5	- 0/00	

Part Nu	mber	Top Mark	Package	Packing Method	Reel Siz	e	Tape Width	ı Qu	antity	
FCPF400			TO-220F	Tube	N/A		N/A	50	50 units	
Electrica	al Char	acteristics T <sub>C</sub> = 25°	C unless oth	nerwise noted.						
Symbol		Parameter		Test Conditions	s	Min.	Тур.	Max.	Unit	
Off Chara	cteristic	S								
BV <sub>DSS</sub>	Drain to	Source Breakdown Voltag	e Vo	<sub>is</sub> = 0 V, I <sub>D</sub> = 1 mA, T <sub>J</sub>	= 25°C	800	-	-	V	
$\Delta BV_{DSS}$	-					-	0.0			
$/\Delta T_{J}$			ID	$I_D = 1 \text{ mA}$ , Referenced to $25^{\circ}$ C			0.8	-	V/º(	
	Zero Ga	Zero Gate Voltage Drain Current		<sub>S</sub> = 800 V, V <sub>GS</sub> = 0 V		-	-	25	μΑ	
I <sub>DSS</sub> Zero G		Sale voltage Brain Guneni		V <sub>DS</sub> = 640 V, T <sub>C</sub> = 125°C		-	-	250	μη	
I <sub>GSS</sub>	Gate to Body Leakage Current		VG	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0 V		-	-	±10	μA	
On Chara	cteristic	s								
				$_{SS} = V_{DS}, I_{D} = 1.1 \text{ mA}$		2.5	-	4.5	1	
V <sub>GS(th)</sub>	Gate Threshold Voltage			$_{SS} = V_{DS}, I_{D} = 0.68 \text{ mA}$		2.5	-	4.5	V	
				$_{SS} = 10 \text{ V}, \text{ I}_{D} = 5.5 \text{ A}$			0.34	0.4	+	
R <sub>DS(on)</sub>	Static D	Static Drain to Source On Resistance		$_{SS} = 10 \text{ V}, \text{ I}_{D} = 7.1 \text{ A}$		-	0.35	0.4	Ω	
				<sub>SS</sub> = 10 V, I <sub>D</sub> = 7.1 A, T	<sub>C</sub> = 150 <sup>o</sup> C	-	0.89	-		
9 <sub>FS</sub>	Forward	d Transconductance		<sub>DS</sub> = 20 V, I <sub>D</sub> = 5.5 A	0	-	12	-	S	
Dynamic (	Charact	aristics			¥					
C <sub>iss</sub>	1	apacitance					1770	2350	pF	
C <sub>oss</sub>		Capacitance	V	V <sub>DS</sub> = 100 V, V <sub>GS</sub> = 0 V, f = 1 MHz		_	51	70	pF	
C <sub>rss</sub>		e Transfer Capacitance	f =			-	0.5	-	pF	
C <sub>oss</sub>	Output Capacitance		Ve	<sub>DS</sub> = 480 V, V <sub>GS</sub> = 0 V, <sup>1</sup>	f = 1 MHz	-	28	-	pF	
			$r_{OS} = 0 \text{ V to } 480 \text{ V}, \text{ V}_{GS}$		-	138	-	pF		
C <sub>oss(eff.)</sub> Q <sub>g(tot)</sub>					-	43	56	nC		
$Q_{gs}$		Source Gate Charge		V <sub>DS</sub> = 640 V, I <sub>D</sub> = 11 A, V <sub>GS</sub> = 10 V (Note 4)		-	8.6	-	nC	
Q <sub>gd</sub>		Drain "Miller" Charge	• (			-	17	-	nC	
ESR	Equivalent Series Resistance		f =	1 MHz	, ,	-	2.3	-	Ω	
						-				
Switching	Charac	teristics								
t <sub>d(on)</sub>	Turn-On	urn-On Delay Time				-	20	50	ns	
t <sub>r</sub>	Turn-On	Rise Time	VD	$_{\rm D}$ = 400 V, $I_{\rm D}$ = 11 A,			12	34	ns	
t <sub>d(off)</sub>	Turn-Off	Turn-Off Delay Time		$_{\rm SS}$ = 10 V, R <sub>g</sub> = 4.7 $\Omega$		-	51	112	ns	
t <sub>f</sub>	Turn-Off Fall Time				(Note 4)	-	2.6	15	ns	
Drain-Sou	rce Dio	de Characteristics								
I <sub>S</sub>	Maximum Continuous Drain to Source Dio			orward Current		-	-	11	А	
I <sub>SM</sub>	Maximum Pulsed Drain to Source Diode F					-	-	33	A	
V <sub>SD</sub>		Source Diode Forward Vol		<sub>SS</sub> = 0 V, I <sub>SD</sub> = 11 A		-	-	1.2	V	
t <sub>rr</sub>		Recovery Time	-	<sub>as</sub> = 0 V, I <sub>sp</sub> = 11 A,		-	395	-	ns	
Q <sub>rr</sub>		Recovery Charge		$dI_{\rm F}/dt = 100 \text{ A/}\mu\text{s}$			7.4	-	μC	

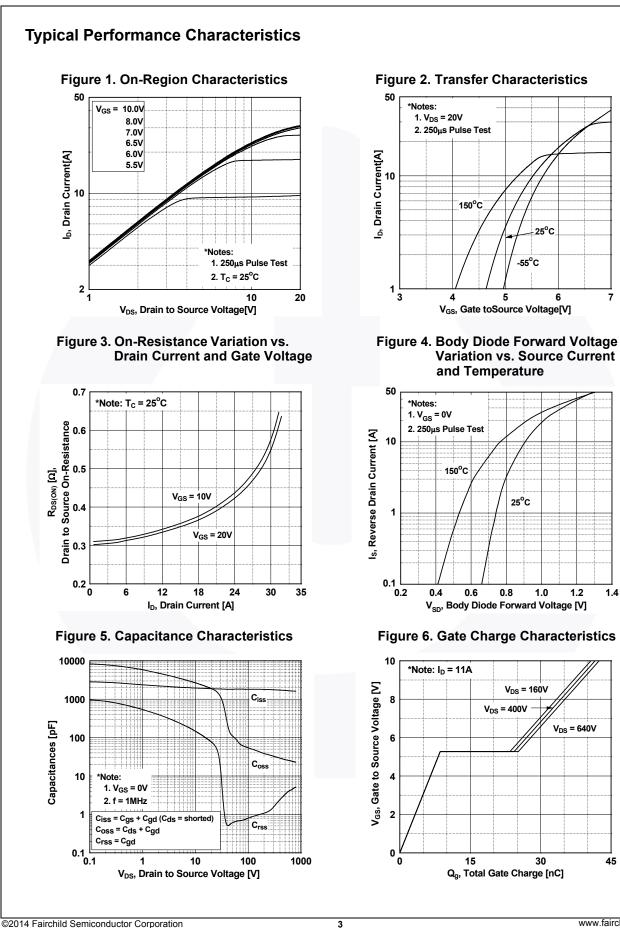
1. Repetitive rating: pulse-width limited by maximum junction temperature.

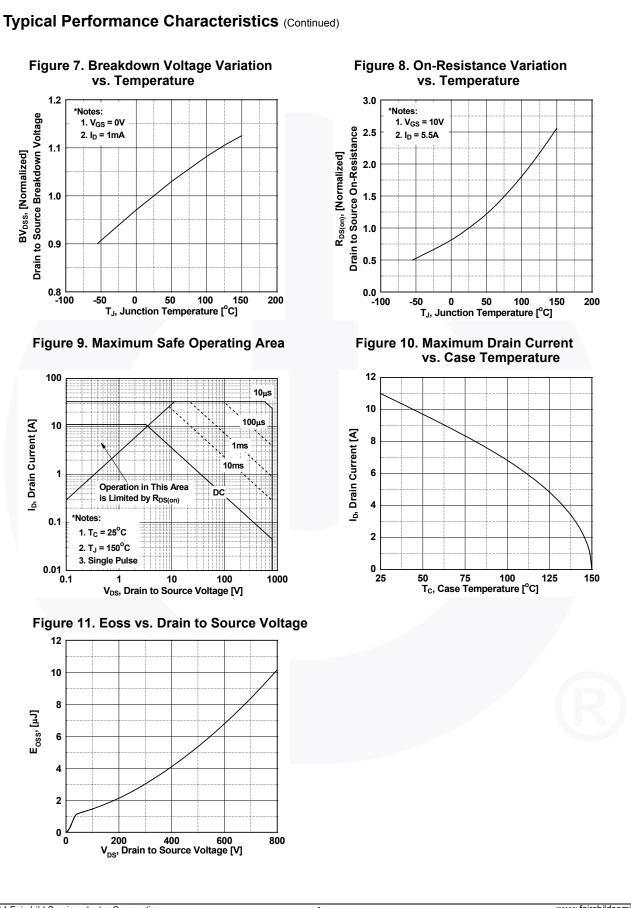
2. I\_{AS} = 2.2 A, V\_{DD} = 50 V, R\_G = 25  $\Omega,$  starting T\_J = 25°C.

3. I\_{SD}  $\leq$  11 A, di/dt  $\leq$  200 A/µs, V\_{DD}  $\leq$  BV\_{DSS}, starting T\_J = 25°C.

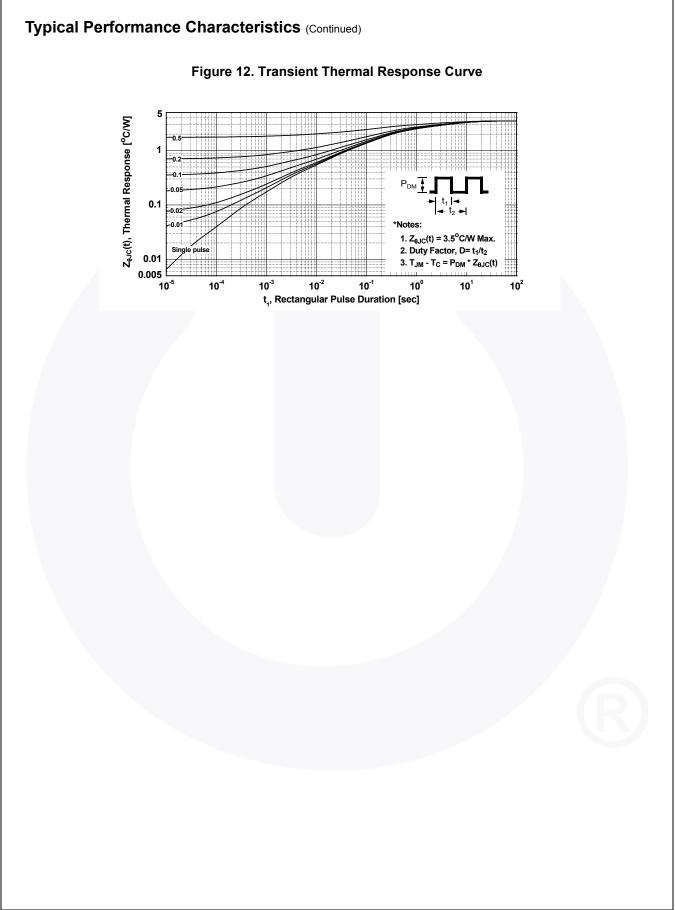
4. Essentially independent of operating temperature typical characteristics.

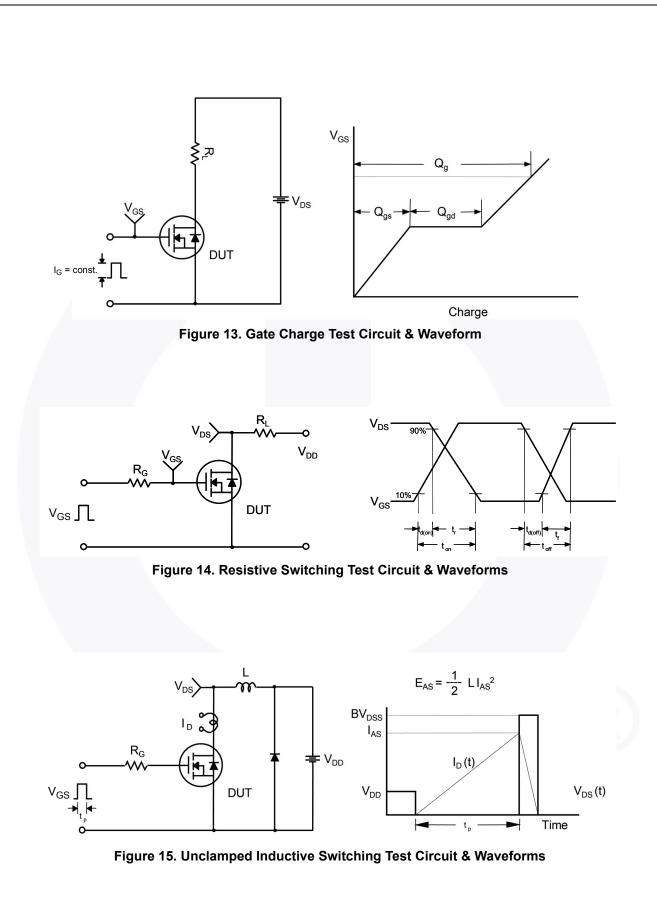
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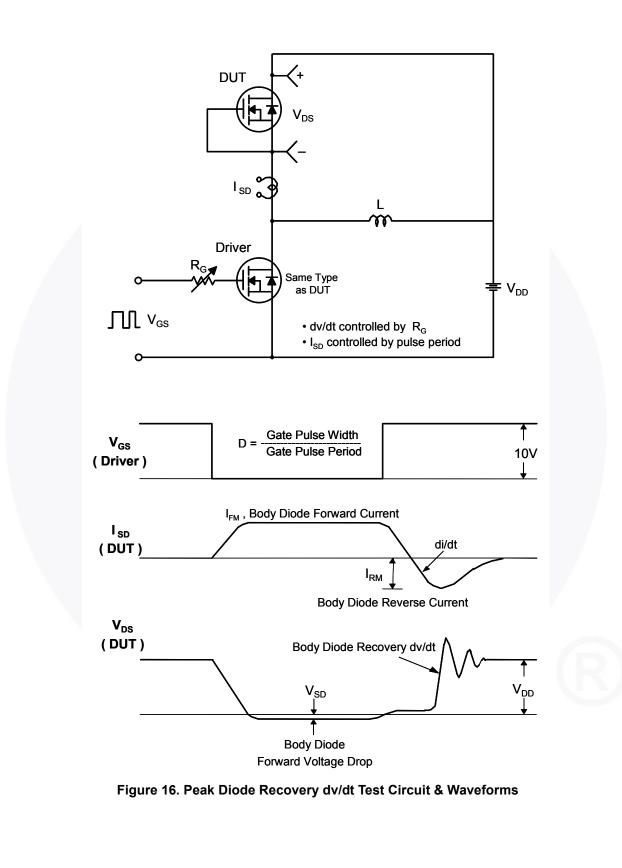
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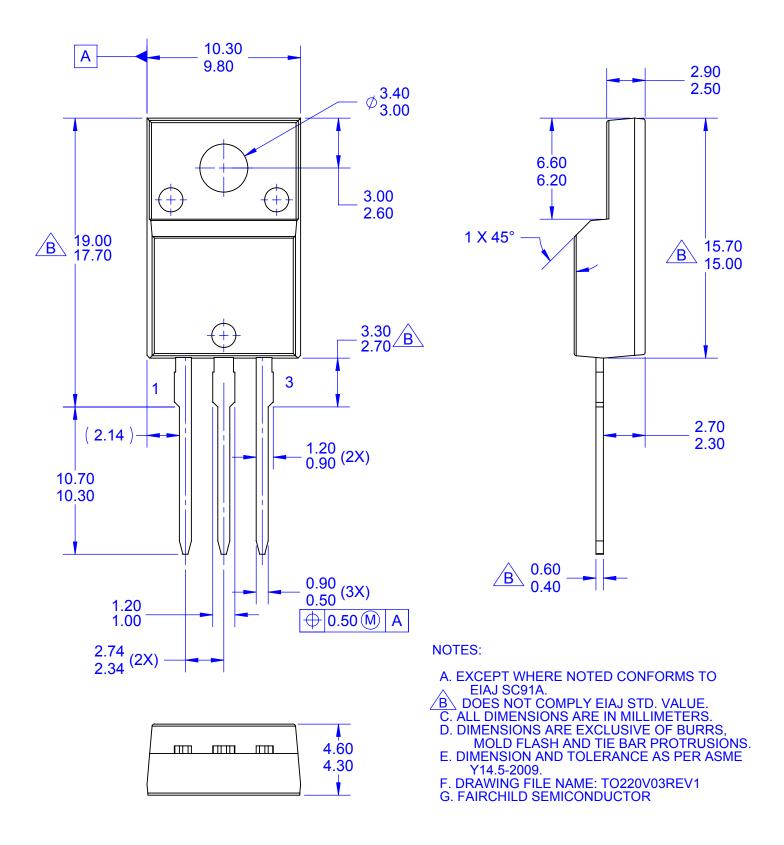




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